

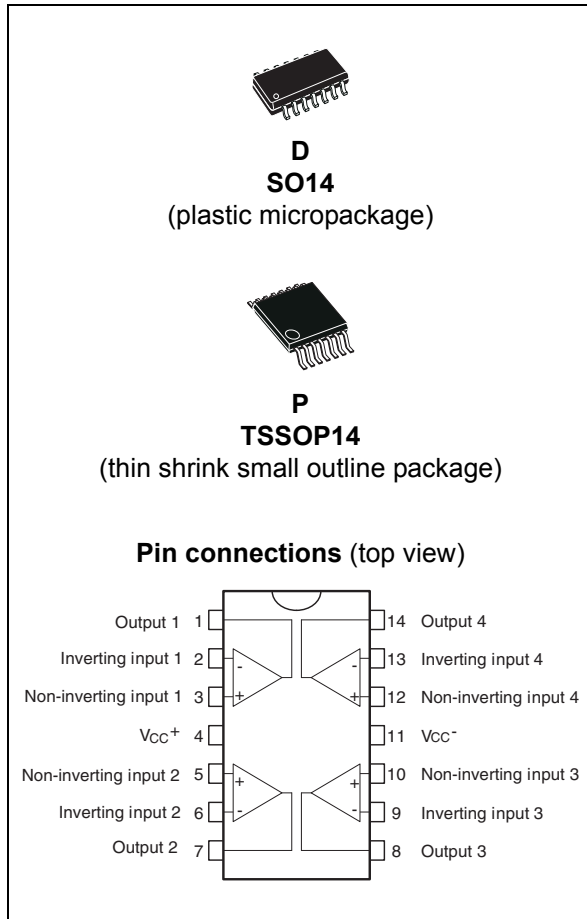


THE DATASHEET OF TS924AIYDT



Rail-to-rail output current quad operational amplifier

Datasheet - production data



Features

- Rail-to-rail input and output
- Low noise: $9 \text{ nV}/\sqrt{\text{Hz}}$
- Low distortion
- High output current: 80 mA (able to drive 32Ω loads)
- High-speed: 4 MHz, $1.3 \text{ V}/\mu\text{s}$
- Operating range from 2.7 V to 12 V
- Low input offset voltage: 900 μV max. (TS924A)

- ESD internal protection: 3 kV
- Latch-up immunity
- Macromodel included in this specification

Related products

- See the TS921 device for the single version and the TS922 device for the dual version
- See the TSX56x series for smaller packages

Applications

- Headphone amplifiers
- Piezoelectric speaker drivers
- Sound cards
- MPEG boards, multimedia systems
- Line drivers, buffers
- Cordless telephones and portable communication equipment
- Instrumentation with low noise as key factor

Description

The TS924 and TS924A devices are rail-to-rail quad BiCMOS operational amplifiers optimized and fully specified for 3 V and 5 V operation.

High output current allows low load impedances to be driven.

The TS924 and TS924A devices exhibit a very low noise, low distortion, low offset, and high output current capability, making these devices an excellent choice for high-quality, low-voltage, and battery-operated audio systems.

The devices are stable for capacitive loads up to 500 pF.

Contents

| | | |
|----------|--|-----------|
| 1 | Absolute maximum ratings and operating conditions | 3 |
| 2 | Electrical characteristics | 4 |
| 3 | Macromodel | 10 |
| 3.1 | Important note concerning this macromodel | 10 |
| 3.2 | Electrical characteristics from macromodelization | 10 |
| 3.3 | Macromodel code | 11 |
| 4 | Package information | 13 |
| 4.1 | SO14 package information | 14 |
| 4.2 | TSSOP14 package information | 15 |
| 5 | Ordering information | 16 |
| 6 | Revision history | 17 |

1 Absolute maximum ratings and operating conditions

Table 1. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|------------|---|------------------------------------|------|
| V_{CC} | Supply voltage ⁽¹⁾ | 14 | V |
| V_{id} | Differential input voltage ⁽²⁾ | ± 1 | |
| V_{in} | Input voltage ⁽³⁾ | $V_{CC-} - 0.3$ to $V_{CC+} + 0.3$ | |
| T_{stg} | Storage temperature | -65 to +150 | °C |
| T_j | Maximum junction temperature | 150 | |
| R_{thja} | Thermal resistance junction-to-ambient ⁽⁴⁾ | | °C/W |
| | SO14 TSSOP14 | 66 100 | |
| ESD | HBM: human body model ⁽⁵⁾ | 3 | kV |
| | MM: machine model ⁽⁶⁾ | 100 | V |
| | CDM: charged device model ⁽⁷⁾ SO14 TSSOP14 | 1.5 1 | kV |
| | Output short-circuit duration | See footnote ⁽⁸⁾ | |
| | Latch-up immunity | 200 | mA |
| | Soldering temperature (10 sec.), leaded version | 250 | °C |
| | Soldering temperature (10 sec.), unleaded version | 260 | |

- All voltage values, except the differential voltage, are with respect to network ground terminal.
- The differential voltage is the non-inverting input terminal with respect to the inverting input terminal. If $V_{id} > \pm 1$ V, the maximum input current must not exceed ± 1 mA. In this case ($V_{id} > \pm 1$ V), an input series resistor must be added to limit input current.
- Do not exceed 14 V.
- Short-circuits can cause excessive heating and destructive dissipation. R_{th} are typical values.
- Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 k Ω resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
- Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.
- Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to ground through only one pin. This is done for all pins.
- There is no short-circuit protection inside the device: short-circuits from the output to V_{CC} can cause excessive heating. The maximum output current is approximately 80 mA, independent of the magnitude of V_{CC} . Destructive dissipation can result from simultaneous short-circuits on all amplifiers.

Table 2. Operating conditions

| Symbol | Parameter | Value | Unit |
|------------|--------------------------------------|------------------------------------|------|
| V_{CC} | Supply voltage | 2.7 to 12 | V |
| V_{icm} | Common mode input voltage range | $V_{CC-} - 0.2$ to $V_{CC+} + 0.2$ | |
| T_{oper} | Operating free air temperature range | -40 to +125 | °C |

2 Electrical characteristics

Table 3. Electrical characteristics at $V_{CC+} = +3\text{ V}$ with $V_{CC-} = 0\text{ V}$, $V_{icm} = V_{CC+}/2$, $T_{amb} = 25\text{ °C}$, and R_L connected to $V_{CC+}/2$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|-----------------------|---|--------------|-----------------|------------|--------------------------------------|
| DC performance | | | | | |
| V_{io} | Input offset voltage TS924 TS924A $T_{min} \leq T_{amb} \leq T_{max}$ | | | 3 0.9 | mV |
| | TS924 TS924A | | | 5 1.8 | |
| DV_{io} | Input offset voltage drift | | 2 | | $\mu\text{V}/\text{°C}$ |
| I_{io} | Input offset current - $T_{min} \leq T_{amb} \leq T_{max}$ | | 1 | 30 | nA |
| I_{ib} | Input bias current - $T_{min} \leq T_{amb} \leq T_{max}$ | | 15 | 100 | |
| CMR | V_{icm} from 0 to 3 V $T_{min} \leq T_{amb} \leq T_{max}$ | 60 | 80 | | dB |
| | | 56 | | | |
| SVR | Supply voltage rejection ratio - $V_{CC+} = 2.7$ to 3.3 V $T_{min} \leq T_{amb} \leq T_{max}$ | 60 60 | 85 | | |
| A_{vd} | Large signal voltage gain ($V_{out} = 2 V_{pk-pk}$) $R_L = 10\text{ k}\Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 600\ \Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 32\ \Omega$ | 70 | 200 35 16 | | V/mV |
| | | 15 | | | |
| | | | | | |
| V_{OH} | High level output voltage $R_L = 10\text{ k}\Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 600\ \Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 32\ \Omega$ | 2.90 2.87 | 2.63 | | V |
| | | | | | |
| V_{OL} | Low level output voltage $R_L = 10\text{ k}\Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 600\ \Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 32\ \Omega$ | | 180 | 50 100 | mV |
| | | | | | |
| I_o | Output short-circuit current | 50 | 80 | | mA |
| I_{CC} | Supply current /operator - no load, $V_{out} = V_{CC+}/2$ $T_{min} \leq T_{amb} \leq T_{max}$ | | 1 | 1.5 1.6 | |
| AC performance | | | | | |
| GBP | Gain bandwidth product - $R_L = 600\ \Omega$ | | 4 | | MHz |
| ϕ_m | Phase margin at unit gain - $R_L = 600\ \Omega$, $C_L = 100\text{ pF}$ | | 68 | | Degrees |
| G_m | Gain margin - $R_L = 600\ \Omega$, $C_L = 100\text{ pF}$ | | 12 | | dB |
| SR | Slew rate | 0.7 | 1.3 | | V/ μs |
| e_n | Equivalent input noise voltage - $f = 1\text{ kHz}$ | | 9 | | $\frac{\text{nV}}{\sqrt{\text{Hz}}}$ |

Table 3. Electrical characteristics at $V_{CC+} = +3\text{ V}$ with $V_{CC-} = 0\text{ V}$, $V_{icm} = V_{CC+}/2$, $T_{amb} = 25\text{ °C}$, and R_L connected to $V_{CC+}/2$ (unless otherwise specified) (continued)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|--------|---|------|-------|------|------|
| THD | Total harmonic distortion $V_{out} = 2 V_{pk-pk}$, $F = 1\text{ kHz}$, $A_v = 1$, $R_L = 600\ \Omega$ | | 0.005 | | % |
| C_s | Channel separation | | 120 | | dB |

Table 4. $V_{CC+} = +5\text{ V}$, $V_{CC-} = 0\text{ V}$, $V_{icm} = V_{CC}/2$, $T_{amb} = 25\text{ }^\circ\text{C}$, R_L connected to $V_{CC}/2$
(unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|-----------------------|--|---|-----------------|------------|--------------------------------------|
| DC performance | | | | | |
| V_{io} | Input offset voltage TS924 TS924A $T_{min} \leq T_{amb} \leq T_{max}$ | | | 3 0.9 | mV |
| | TS924 TS924A | | | 5 1.8 | |
| DV_{io} | Input offset voltage drift | | 2 | | $\mu\text{V}/^\circ\text{C}$ |
| I_{io} | Input offset current - $T_{min} \leq T_{amb} \leq T_{max}$ | | 1 | 30 | nA |
| I_{ib} | Input bias current - $T_{min} \leq T_{amb} \leq T_{max}$ | | 15 | 100 | |
| CMR | V_{icm} from 0 to 5 V $T_{min} \leq T_{amb} \leq T_{max}$ | 60 56 | 80 | | dB |
| | SVR | Supply voltage rejection ratio - $V_{CC+} = 3\text{ V to } 5\text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$ | 60 60 | 85 | |
| A_{vd} | Large signal voltage gain ($V_{out} = 2V_{pk-pk}$) $R_L = 10\text{ k}\Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 600\ \Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 32\ \Omega$ | 70 20 | 200 40 17 | | V/mV |
| V_{OH} | High level output voltage $R_L = 10\text{ k}\Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 600\ \Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 32\ \Omega$ | 4.90 4.85 | 4.4 | | V |
| V_{OL} | Low level output voltage $R_L = 10\text{ k}\Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 600\ \Omega$, $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 32\ \Omega$ | | 300 | 50 120 | mV |
| I_o | Output short-circuit current | 50 | 80 | | mA |
| I_{CC} | Supply current / operator - no load, $V_{out} = V_{CC+}/2$ $T_{min} \leq T_{amb} \leq T_{max}$ | | 1 | 1.5 1.6 | |
| AC performance | | | | | |
| GBP | Gain bandwidth product - $R_L = 600\ \Omega$ | | 4 | | MHz |
| ϕ_m | Phase margin at unit gain - $R_L = 600\ \Omega$, $C_L = 100\ \text{pF}$ | | 68 | | Degrees |
| G_m | Gain margin - $R_L = 600\ \Omega$, $C_L = 100\ \text{pF}$ | | 12 | | dB |
| SR | Slew rate | 0.7 | 1.3 | | V/ μs |
| e_n | Equivalent input noise voltage - $f = 1\text{ kHz}$ | | 9 | | $\frac{\text{nV}}{\sqrt{\text{Hz}}}$ |
| THD | Total harmonic distortion $V_{out} = 2\text{ V}_{pk-pk}$, $F = 1\text{ kHz}$, $A_v = 1$, $R_L = 600\ \Omega$ | | 0.005 | | % |
| C_s | Channel separation | | 120 | | dB |

Figure 1. Output short-circuit current vs. output voltage ($V_{CC} = 0/12\text{ V}$)

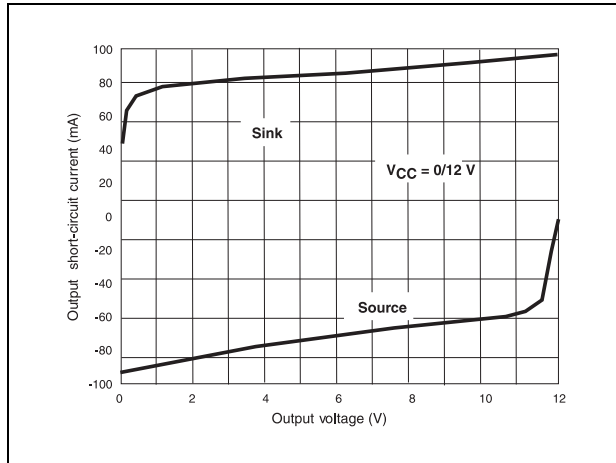


Figure 2. Output short-circuit current vs. output voltage ($V_{CC} = 0/3\text{ V}$)

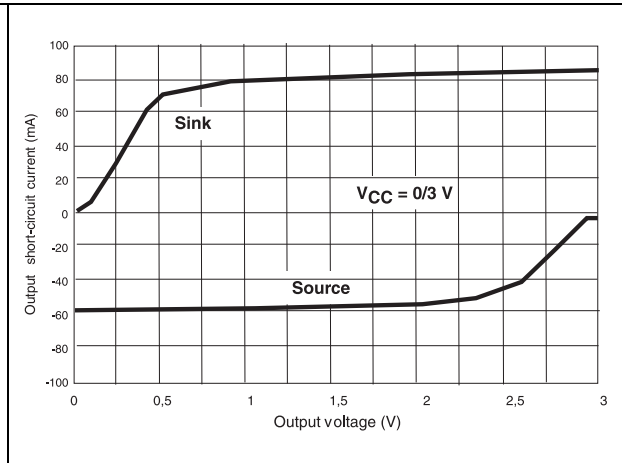


Figure 3. Voltage gain and phase vs. frequency ($C_L = 500\text{ pF}$, $V_{CC} = \pm 1.5\text{ V}$)

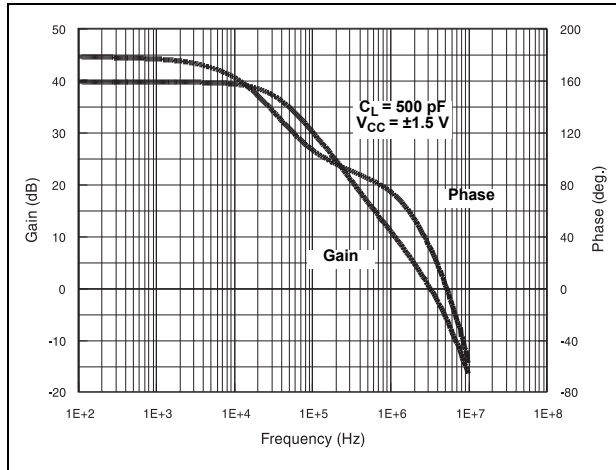


Figure 4. Output short-circuit current vs. output voltage ($V_{CC} = 0/5\text{ V}$)

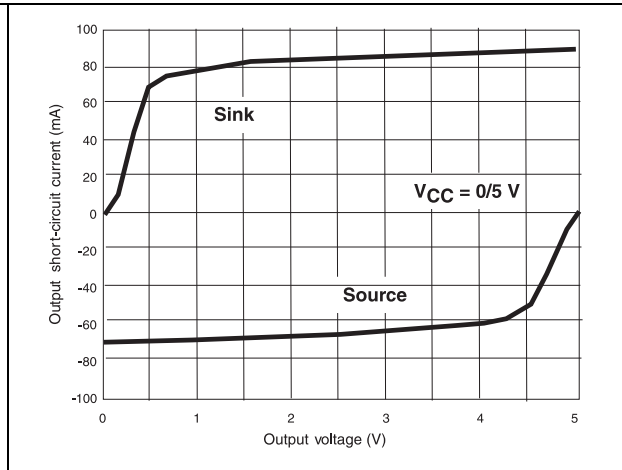


Figure 5. Voltage gain and phase vs. frequency ($R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$, $V_{CC} = \pm 1.5\text{ V}$)

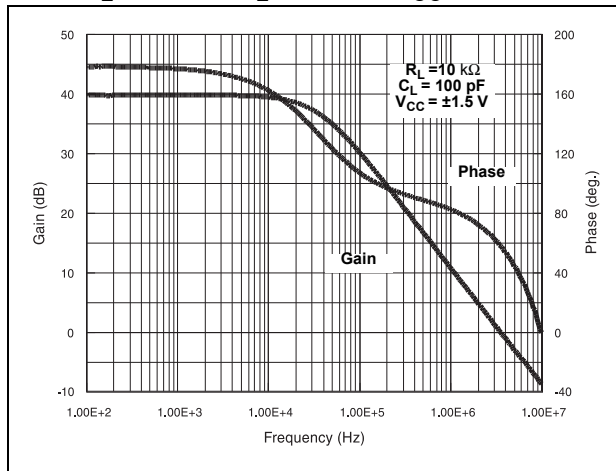


Figure 6. THD + noise vs. frequency ($R_L = 2\text{ k}\Omega$, $V_O = 10\text{ Vpp}$, $V_{CC} = \pm 6\text{ V}$, $A_v = -1$)

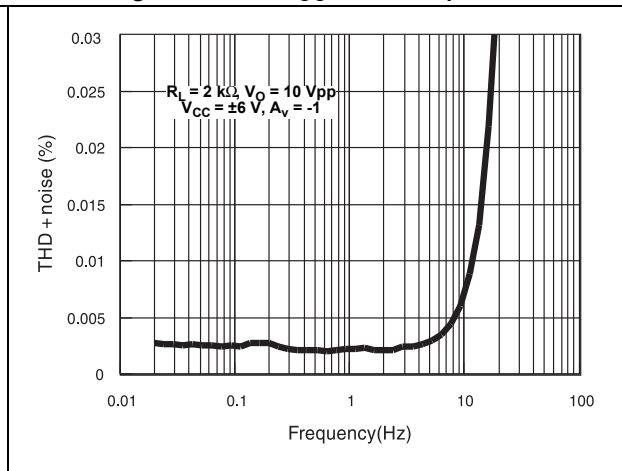


Figure 7. THD + noise vs. frequency ($R_L = 2\text{ k}\Omega$, $V_O = 10\text{ Vpp}$, $V_{CC} = \pm 6\text{ V}$, $A_V = 1$)

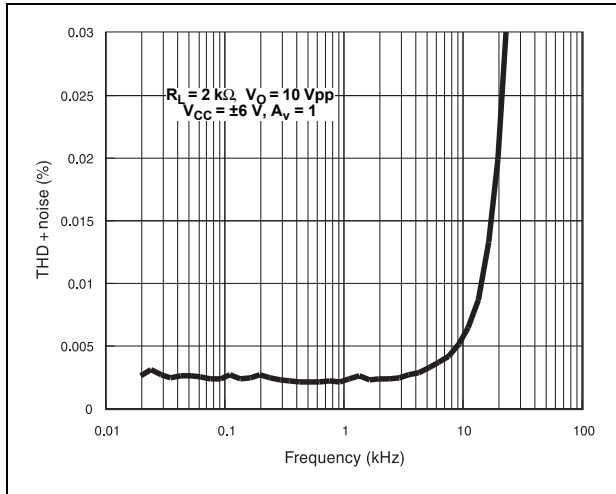


Figure 8. THD + noise vs. frequency ($R_L = 32\ \Omega$, $V_O = 2\text{ Vpp}$, $V_{CC} = \pm 1.5\text{ V}$, $A_V = 10$)

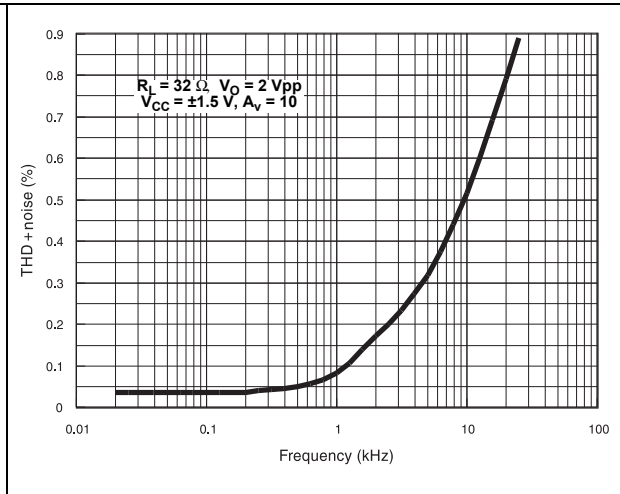


Figure 9. THD + noise vs. V_{out} ($R_L = 32\ \Omega$, $f = 1\text{ kHz}$, $V_{CC} = \pm 1.5\text{ V}$, $A_V = -1$)

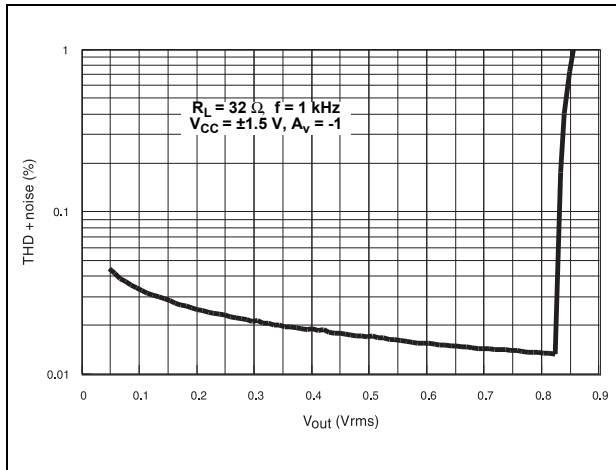


Figure 10. THD + noise vs. frequency ($R_L = 32\ \Omega$, $V_O = 4\text{ Vpp}$, $V_{CC} = \pm 2.5\text{ V}$, $A_V = 1$)

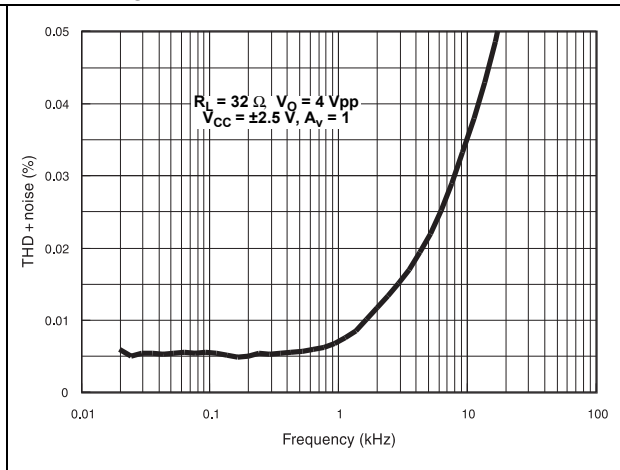


Figure 11. THD + noise vs. V_{out} ($R_L = 600\ \Omega$, $f = 1\text{ kHz}$, $V_{CC} = \pm 1.5\text{ V}$, $A_V = -1$)

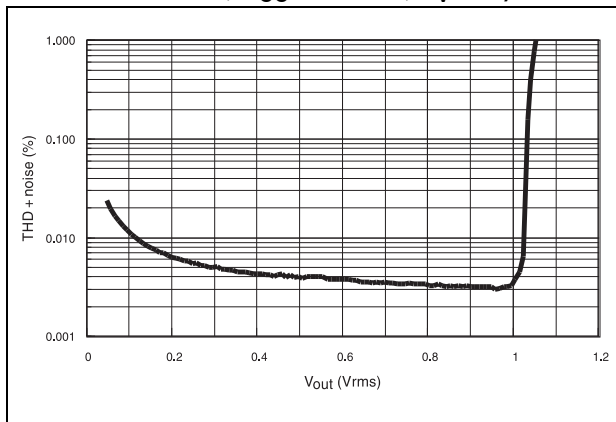


Figure 12. THD + noise vs. V_{out} ($R_L = 2\text{ k}\Omega$, $f = 1\text{ kHz}$, $V_{CC} = \pm 1.5\text{ V}$, $A_V = -1$)

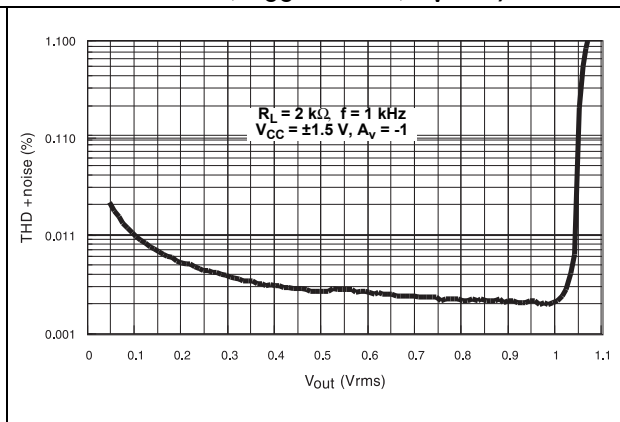
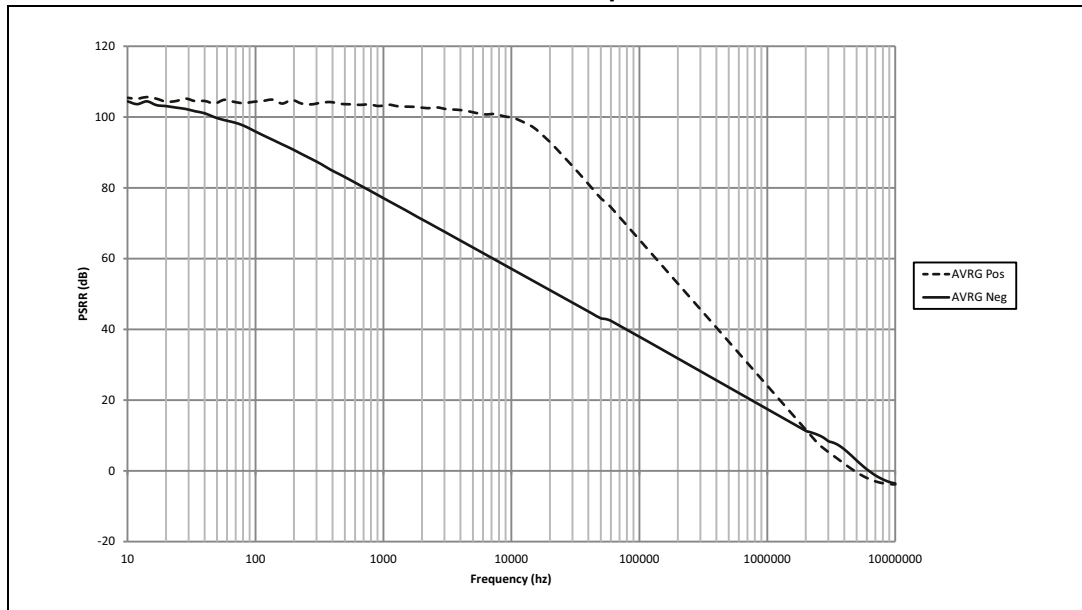


Figure 13. PSRR for TS924/TS924A at $V_{CC} = 5\text{ V}$, $V_{icm} = 2.5\text{ V}$, $T = 25\text{ }^\circ\text{C}$, $R_I = 100\text{ k}\Omega$, and $C_I = 100\text{ pF}$



3 Macromodel

3.1 Important note concerning this macromodel

Note the following remarks before using this macromodel:

- All models are a trade-off between accuracy and complexity (that is, simulation time).
- Macromodels are not a substitute to breadboarding; rather, they confirm the validity of a design approach and help to select surrounding component values.
- A macromodel emulates the **nominal** performance of a **typical** device within **specified operating conditions** (for example, temperature, supply voltage). Thus, the macromodel is often not as exhaustive as the datasheet, its purpose is to illustrate the main parameters of the product.

Data derived from macromodels used outside of the specified conditions (such as V_{CC} and temperature) or worse, outside of the device operating conditions (such as V_{CC} and V_{icm}), are not reliable in any way.

[Section 3.2](#) presents the electrical characteristics resulting from the use of these macromodels.

3.2 Electrical characteristics from macromodelization

Table 5. Macromodel simulation at $V_{CC+} = 3\text{ V}$, $V_{CC-} = 0\text{ V}$, R_L , C_L connected to $V_{CC}/2$, and $T_{amb} = 25\text{ °C}$ (unless otherwise specified)

| Symbol | Conditions | Value | Unit |
|--------------|---|-------------|------------|
| V_{io} | | 0 | mV |
| A_{vd} | $R_L = 10\text{ k}\Omega$ | 200 | V/mV |
| I_{CC} | No load, per operator | 1.2 | mA |
| V_{icm} | | -0.2 to 3.2 | V |
| V_{OH} | $R_L = 10\text{ k}\Omega$ | 2.95 | |
| V_{OL} | $R_L = 10\text{ k}\Omega$ | 25 | mV |
| I_{sink} | $V_O = 3\text{ V}$ | 80 | mA |
| I_{source} | $V_O = 0\text{ V}$ | 80 | |
| GBP | $R_L = 600\text{ k}\Omega$ | 4 | MHz |
| SR | $R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$ | 1 | V/ μ s |
| ϕ_m | $R_L = 600\text{ k}\Omega$ | 68 | Degrees |

3.3 Macromodel code

```

** Standard Linear Ics Macromodels, 1996.
** CONNECTIONS:
* 1 INVERTING INPUT
* 2 NON-INVERTING INPUT
* 3 OUTPUT
* 4 POSITIVE POWER SUPPLY
* 5 NEGATIVE POWER SUPPLY

.SUBCKT TS92X 1 2 3 4 5
*
.MODEL MDTH D IS=1E-8 KF=2.664234E-16 CJO=10F
*
* INPUT STAGE
CIP 2 5 1.000000E-12
CIN 1 5 1.000000E-12
EIP 10 5 2 5 1
EIN 16 5 1 5 1
RIP 10 11 8.125000E+00
RIN 15 16 8.125000E+00
RIS 11 15 2.238465E+02
DIP 11 12 MDTH 400E-12
DIN 15 14 MDTH 400E-12
VOFP 12 13 DC 153.5u
VOFN 13 14 DC 0
IPOL 13 5 3.200000E-05
CPS 11 15 1e-9
DINN 17 13 MDTH 400E-12
VIN 17 5 -0.100000e+00
DINR 15 18 MDTH 400E-12
VIP 4 18 0.400000E+00
FCP 4 5 VOFP 1.865000E+02
FCN 5 4 VOFN 1.865000E+02
FIBP 2 5 VOFP 6.250000E-03
FIBN 5 1 VOFN 6.250000E-03
* GM1 STAGE *****
FGM1P 119 5 VOFP 1.1
FGM1N 119 5 VOFN 1.1
RAP 119 4 2.6E+06
RAN 119 5 2.6E+06
* GM2 STAGE *****
G2P 19 5 119 5 1.92E-02
G2N 19 5 119 4 1.92E-02
R2P 19 4 1E+07

```

```
R2N 19 5 1E+07
*****
VINT1 500 0 5
GCONVP 500 501 119 4 19.38
VP 501 0 0
GCONVN 500 502 119 5 19.38
VN 502 0 0
***** orientation isink isource *****
VINT2 503 0 5
FCOPY 503 504 VOUT 1
DCOPYP 504 505 MDTH 400E-9
VCOPYP 505 0 0
DCOPYN 506 504 MDTH 400E-9
VCOPYN 0 506 0
*****
F2PP 19 5 poly(2) VCOPYP VP 0 0 0 0 0.5
F2PN 19 5 poly(2) VCOPYP VN 0 0 0 0 0.5
F2NP 19 5 poly(2) VCOPYN VP 0 0 0 0 1.75
F2NN 19 5 poly(2) VCOPYN VN 0 0 0 0 1.75
* COMPENSATION *****
CC 19 119 25p
* OUTPUT *****
DOPM 19 22 MDTH 400E-12
DONM 21 19 MDTH 400E-12
HOPM 22 28 VOUT 6.250000E+02
VIPM 28 4 5.000000E+01
HONM 21 27 VOUT 6.250000E+02
VINM 5 27 5.000000E+01
VOUT 3 23 0
ROUT 23 19 6
COUT 3 5 1.300000E-10
DOP 19 25 MDTH 400E-12
VOP 4 25 1.052
DON 24 19 MDTH 400E-12
VON 24 5 1.052
.ENDS ;TS92X
```

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

4.1 SO14 package information

Figure 14. SO14 package outline

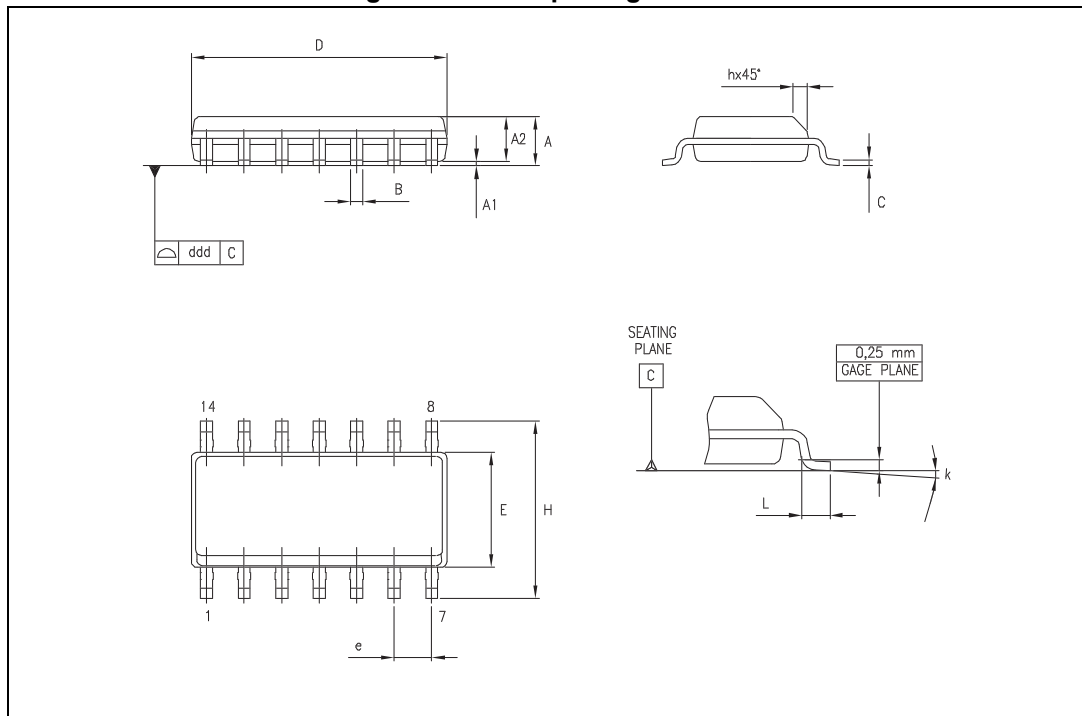


Table 6. SO14 package mechanical data

| Symbol | Dimensions | | | | | |
|--------|-------------|------|------|--------|------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 1.35 | | 1.75 | 0.05 | | 0.068 |
| A1 | 0.10 | | 0.25 | 0.004 | | 0.009 |
| A2 | 1.10 | | 1.65 | 0.04 | | 0.06 |
| B | 0.33 | | 0.51 | 0.01 | | 0.02 |
| C | 0.19 | | 0.25 | 0.007 | | 0.009 |
| D | 8.55 | | 8.75 | 0.33 | | 0.34 |
| E | 3.80 | | 4.0 | 0.15 | | 0.15 |
| e | | 1.27 | | | 0.05 | |
| H | 5.80 | | 6.20 | 0.22 | | 0.24 |
| h | 0.25 | | 0.50 | 0.009 | | 0.02 |
| L | 0.40 | | 1.27 | 0.015 | | 0.05 |
| k | 8° (max.) | | | | | |
| ddd | | | 0.10 | | | 0.004 |

4.2 TSSOP14 package information

Figure 15. TSSOP14 package outline

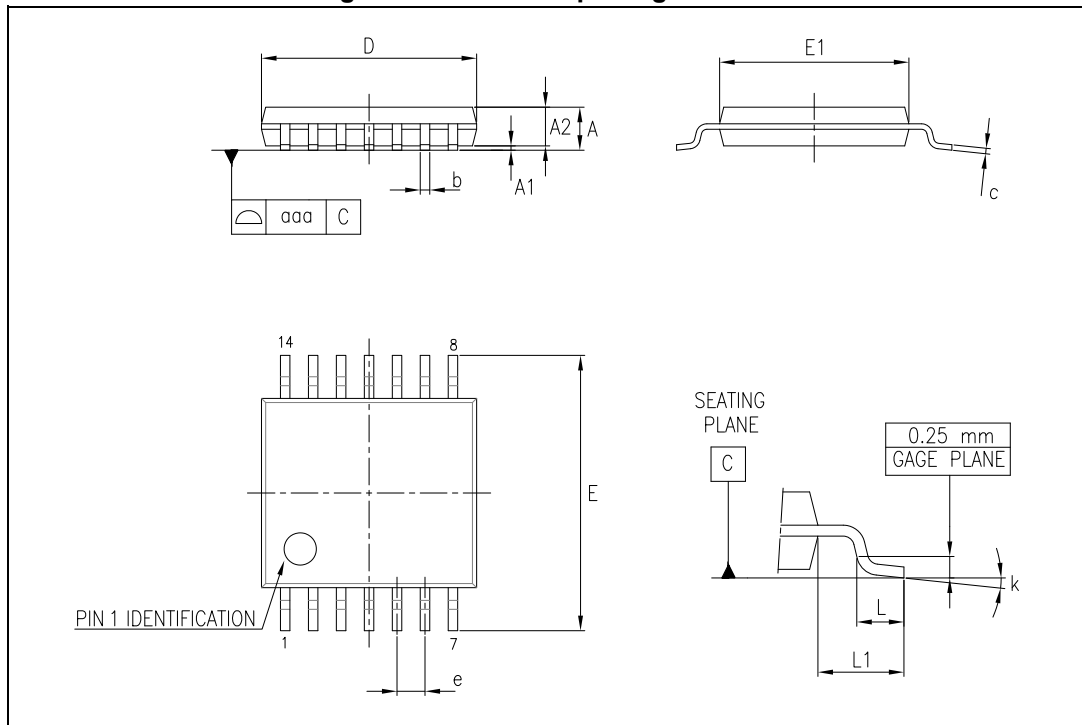


Table 7. TSSOP14 package mechanical data

| Symbol | Dimensions | | | | | |
|--------|-------------|------|------|--------|--------|--------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | | | 1.20 | | | 0.047 |
| A1 | 0.05 | | 0.15 | 0.002 | 0.004 | 0.006 |
| A2 | 0.80 | 1.00 | 1.05 | 0.031 | 0.039 | 0.041 |
| b | 0.19 | | 0.30 | 0.007 | | 0.012 |
| c | 0.09 | | 0.20 | 0.004 | | 0.0089 |
| D | 4.90 | 5.00 | 5.10 | 0.193 | 0.197 | 0.201 |
| E | 6.20 | 6.40 | 6.60 | 0.244 | 0.252 | 0.260 |
| E1 | 4.30 | 4.40 | 4.50 | 0.169 | 0.173 | 0.176 |
| e | | 0.65 | | | 0.0256 | |
| L | 0.45 | 0.60 | 0.75 | 0.018 | 0.024 | 0.030 |
| L1 | | 1.00 | | | 0.039 | |
| k | 0° | | 8° | 0° | | 8° |
| aaa | | | 0.10 | | | 0.004 |

5 Ordering information

Table 8. Order codes

| Order code | Temperature range | Package | Packaging | Marking |
|---------------------------|-------------------|-------------------------------|--------------------------|---------|
| TS924ID TS924IDT | -40 °C, 125 °C | SO14 | Tube or tape and reel | 924I |
| TS924AID TS924AIDT | | | | 924AI |
| TS924IYDT ⁽¹⁾ | | SO14 (automotive grade) | Tape and reel | 924IY |
| TS924AIYDT ⁽¹⁾ | | | | 924AIY |
| TS924IPT | | TSSOP14 | | 924I |
| TS924AIPT | | | | 924AI |
| TS924IYPT ⁽¹⁾ | | TSSOP14 (automotive grade) | | 924IY |
| TS924AIYPT ⁽¹⁾ | | | | 924AIY |

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q 002 or equivalent.

6 Revision history

Table 9. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 28-May-2001 | 1 | First release. |
| 12-May-2005 | 2 | Modifications on AMR Table on page 3 (explanation of V_{id} and V_{in} limits, ESD MM and CDM values added, R_{thja} added). |
| 31-Jul-2005 | 3 | PPAP references inserted in the datasheet, see order codes table. |
| 30-Nov-2005 | 4 | Package mechanical data modified. TS924IYPT/TS924AYIPT PPAP reference inserted in order code table. Macromodel modified. |
| 11-Mar-2008 | 5 | Added footnotes for automotive grade order codes in Table 8: Order codes . Updated document format. |
| 19-Dec-2008 | 6 | ESD tolerance improved for machine model in Table 1: Absolute maximum ratings . Removed TS914AIN order code and corrected footnotes in Table 8: Order codes . |
| 08-Oct-2009 | 7 | Added part number TS924A on cover page. Added limits on full temperature range in Table 3 and Table 4 . Removed order codes TS924IYD and TS924AIYD from Table 8 . |
| 15-Apr-2011 | 8 | Modified CMR parameter values in Table 3 and Table 4 . |
| 19-May-2011 | 9 | Added A version in title and header. |
| 04-Dec-2012 | 10 | Added DIP14 package to Figure on page 1. Added Related products to Features . Added DIP14 with value for R_{thja} in Table 1 . Added conditions to titles of Figure 1 to Figure 12 . Replaced V_{CC} by V_{CC+} and V_{DD} by V_{CC-} in title of Table 5 . Qualified status of TS924IYPT and TS924AIYPT order codes in Table 8 . Minor corrections throughout document. |
| 05-Jun-2014 | 11 | Removed DIP14 package and order code pertaining to it Added Figure 13 |

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